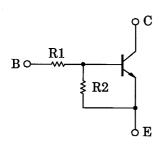
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## RN1301,RN1302,RN1303 RN1304,RN1305,RN1306

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2301~RN2306

### **Equivalent Circuit and Bias Resistor Values**



Type No.	R1 (kΩ)	R2 (kΩ)		
RN1301	4.7	4.7		
RN1302	10	10		
RN1303	22	22		
RN1304	47	47		
RN1305	2.2	47		
RN1306	4.7	47		

# 1. BASE 2. EMITTER 3. COLLECTOR JEDEC — EIAJ SC-70 TOSHIBA 2-2E1A

Weight: 0.006g

### Maximum Ratings (Ta = 25°C)

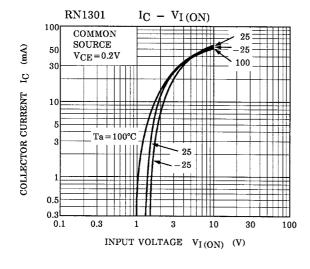
Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN1301~1306	V <sub>CBO</sub>	50	V	
Collector-emitter voltage	1(1001-1000	V <sub>CEO</sub>	50	٧	
Emitter-base voltage	RN1301~1304	V <sub>EBO</sub>	10	V	
Emilier-base voltage	RN1305, 1306	vEBO.	5		
Collector current		I <sub>c</sub>	100	mA	
Collector power dissipation	RN1301~1306	Pc	100	mW	
Junction temperature	1001001000	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

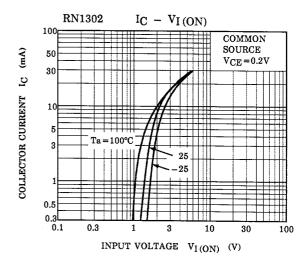


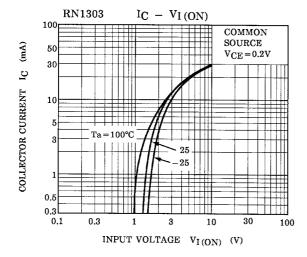
# Electrical Characteristics (Ta = 25°C)

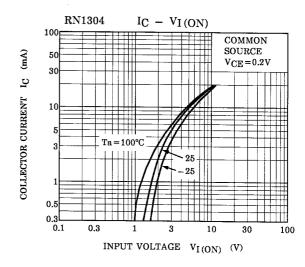
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	DN1201-1206	I <sub>CBO</sub>	_	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	nA
	RN1301~1306	I <sub>CEO</sub>	_	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	_	_	500	
	RN1301	I <sub>EBO</sub>	_	- V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	mA
	RN1302		_		0.38	_	0.71	
Emitter out off ourrent	RN1303		_		0.17	_	0.33	
Emitter cut-off current	RN1304		_		0.082	_	0.15	
	RN1305		_	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145	
	RN1306		_		0.074	_	0.138	
	RN1301		_	_	30	_	_	_
	RN1302		_		50	_	_	
DC surrent main	RN1303	L	_	) 	70	_	_	
DC current gain	RN1304	- h <sub>FE</sub>	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	80	_	_	
	RN1305		_		80	_	_	
	RN1306		_		80	_	_	
Collector-emitter saturation voltage	RN1301~1306	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	٧
	RN1301	VI (ON)	_	- V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.1	_	2.0	. v
	RN1302		_		1.2	_	2.4	
	RN1303		_		1.3	_	3.0	
Input voltage (ON)	RN1304		_		1.5	_	5.0	
	RN1305		_		0.6	_	1.1	
	RN1306		_		0.7	_	1.3	
Input voltage (OFF)	RN1301~1304	V <sub>I (OFF)</sub>	_	- V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	V
input voitage (OFF)	RN1305, 1306		_		0.5	_	0.8	
Translation frequency	RN1301~1306	f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector output capacitance	RN1301~1306	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	-	3	6	pF
Input resistor	RN1301	R1	_	3.29 4.7 7 10 15.4 22 32.9 47 1.54 2.2 3.29 4.7	3.29	4.7	6.11	
	RN1302		_		7	10	13	
	RN1303		_		15.4	22	28.6	
	RN1304		_		61.1	kΩ		
	RN1305		_		1.54	2.2	2.86	
	RN1306		_		3.29	4.7	6.11	
Resistor ratio	RN1301~1305	R1/R2	_	_	0.9	1.0	1.1	_
	RN1305		_		0.0421	0.0468	0.0515	
	RN1306		_		0.09	0.1	0.11	

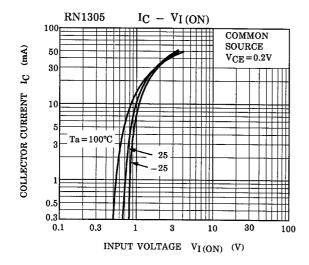
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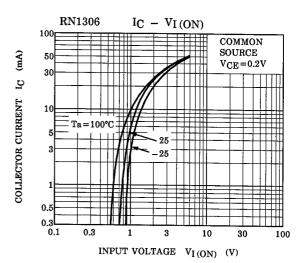


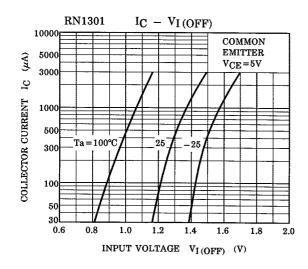


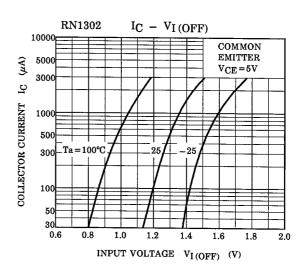


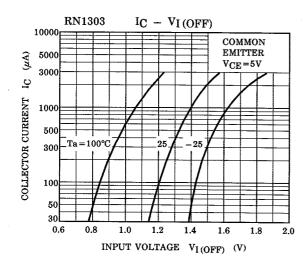


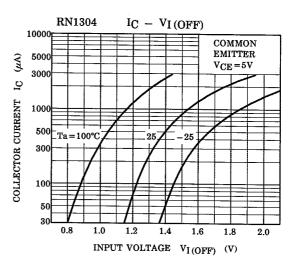


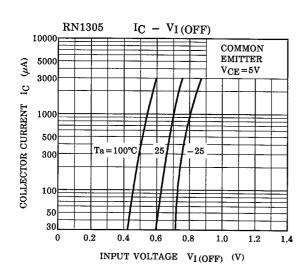


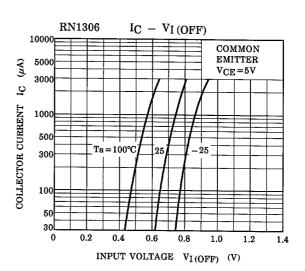


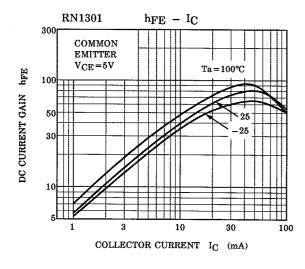


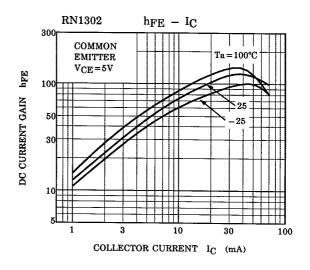


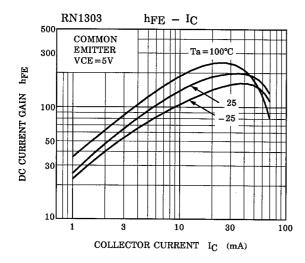


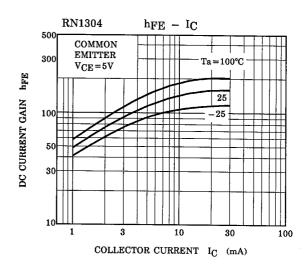


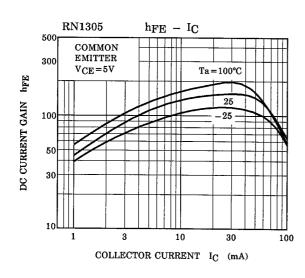


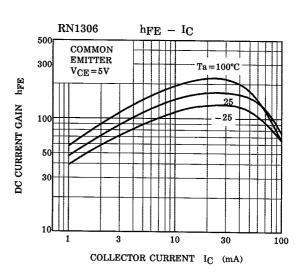












Type Name	Marking
RN1301	Type Name  X A
RN1302	Type Name  X B
RN1303	Type Name  X C
RN1304	Type Name  X D
RN1305	Type Name  X E
RN1306	Type Name  X F

2001-06-07

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